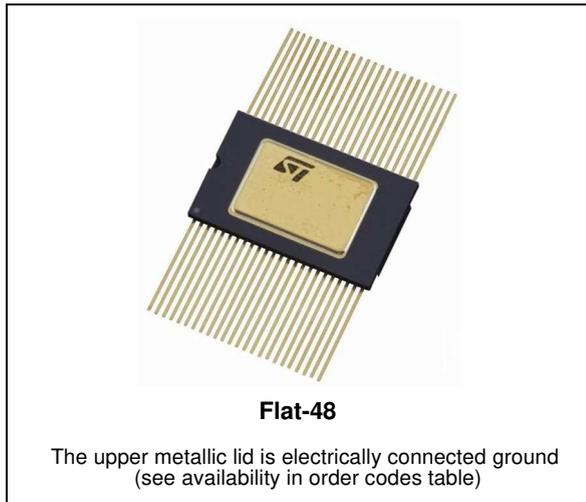

**Rad hard low voltage CMOS 16-bit bus buffer transceiver (3-state)
with 3.6 V tolerant inputs and outputs**

Datasheet - production data

**Description**

The 54VCXHR162245 is a low voltage CMOS 16-bit bus transceiver (3-state) developed with sub-micron silicon gate and five-layer metal wiring C²MOS technology. It is ideal for low power and very high speed 1.8 to 3.6 V applications; it can be interfaced to 3.6 V signal environment for both inputs and outputs. This IC is intended for two-way asynchronous communication between data buses; the direction of data transmission is determined by DIR input. The two enable inputs $n\bar{G}$ can be used to disable the device so that the buses are effectively isolated. The device circuits include 26 Ω series resistance in the A and B port outputs. These resistors reduce the line noise in high speed applications. Bus hold on data inputs is provided in order to eliminate the need for the external pull-up or pull-down resistor. All inputs and outputs are equipped with protection circuits against static discharge, giving them 2 kV ESD immunity and transient excess voltage. All floating bus terminals during high Z state must be held HIGH or LOW.

Features

- 1.8 to 3.6 V operating voltage
- High speed in both A, B outputs:
 - $t_{PD} = 3.4$ ns at $V_{CC} = 3.0$ to 3.6 V
 - $t_{PD} = 4.3$ ns at $V_{CC} = 2.3$ to 2.7 V
- Symmetrical impedance outputs:
 - $|I_{OH}| = I_{OL} = 12$ mA (min.) at $V_{CC} = 3.0$ V
 - $|I_{OH}| = I_{OL} = 8$ mA (min.) at $V_{CC} = 2.3$ V
- Power down protection on inputs and outputs
- 26 Ω series resistors in both A and B port outputs
- Bus hold provided on both sides
- Cold spare function
- Latch-up performance exceeds 300 mA (JESD 17)
- 300 krad(Si) Total ionizing dose (TID)
- No SEL, no SEU and no SET at 110 MeV.cm²/mg LET
- QML-V qualified
- SMD 5962F02508
- Mass:1.50 g

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1 Logic symbols and I/O equivalent circuit

Figure 1. IEC logic symbols

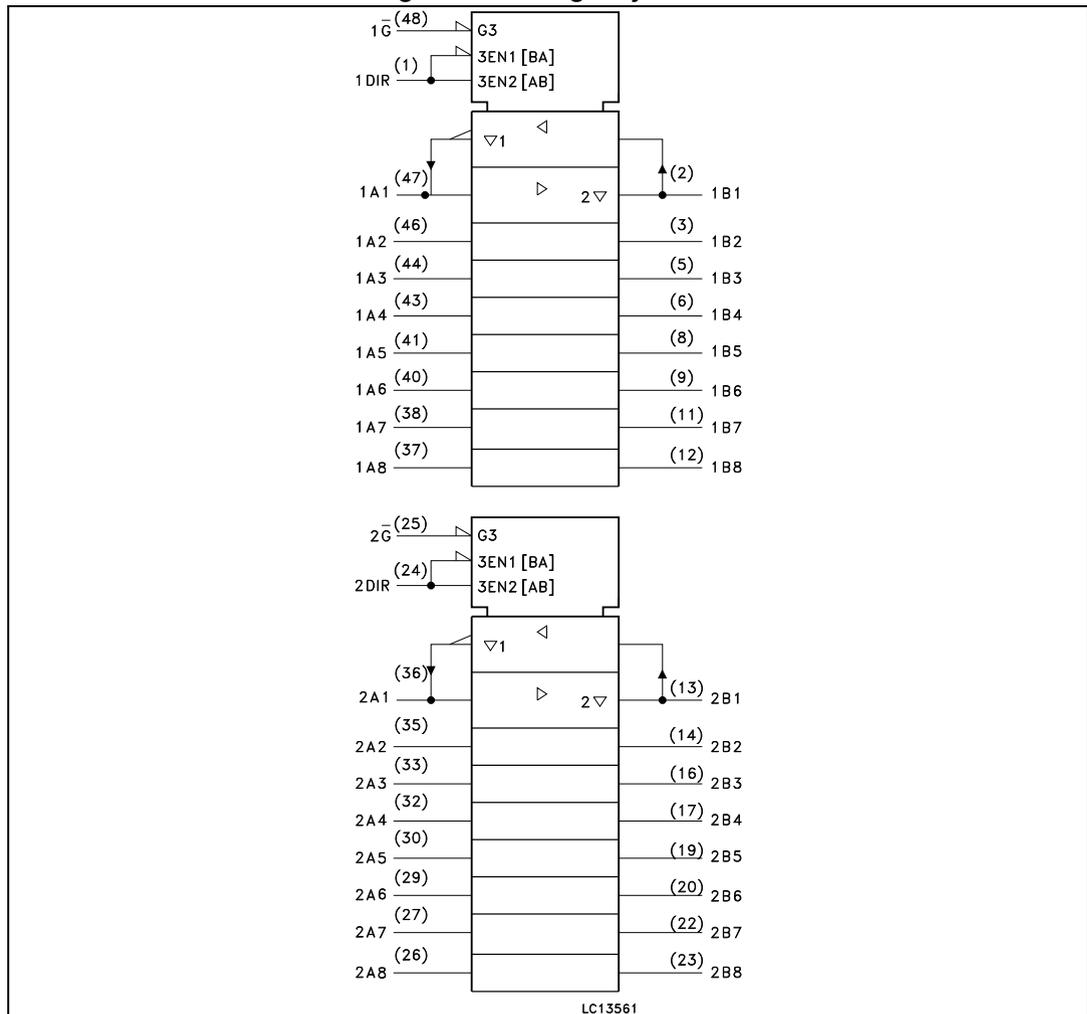
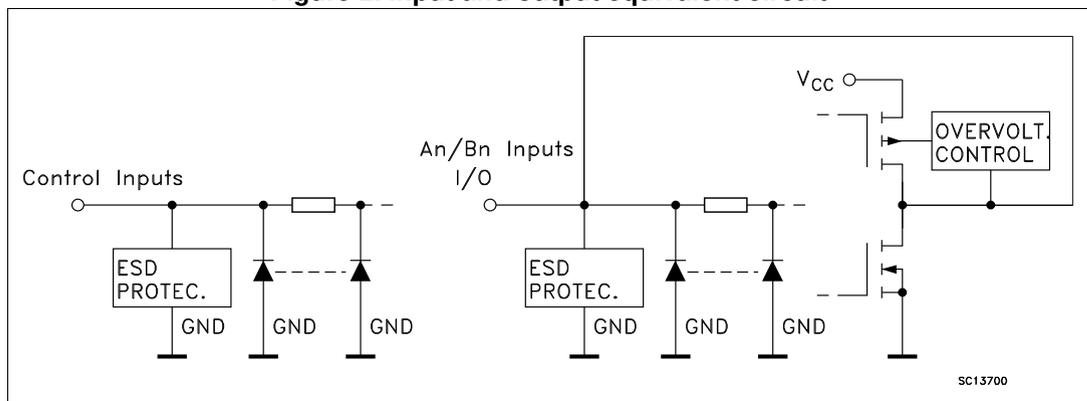


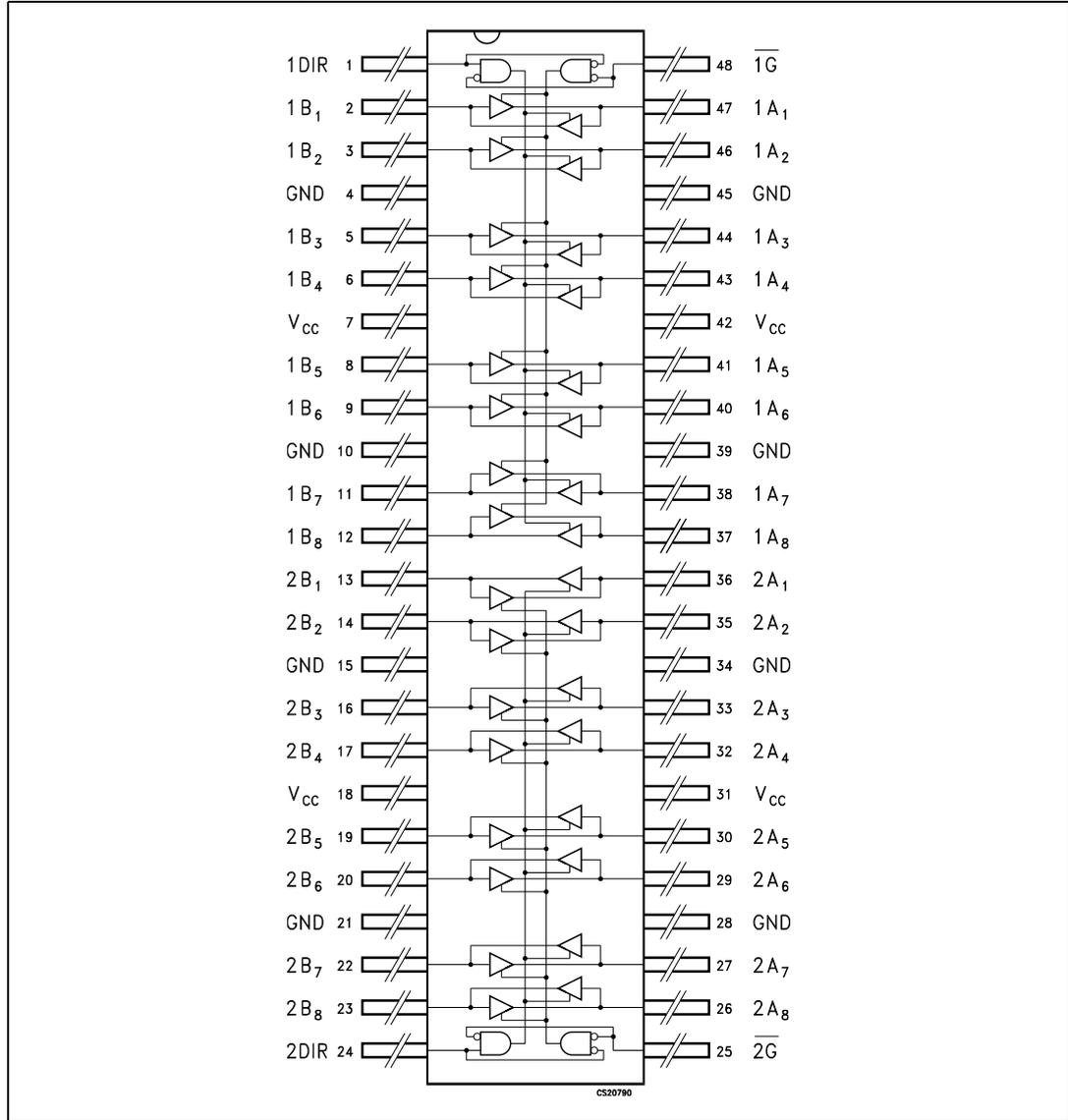
Figure 2. Input and output equivalent circuit



2 Pin settings

2.1 Pin connection

Figure 3. Pin connection (top through view)



2.2 Pin description

Table 1. Pin description

Pin n°	Symbol	Name and function
1	1DIR	Directional control
2, 3, 5, 6, 8, 9, 11, 12	1B1 to 1B8	Data inputs/outputs
13, 14, 16, 17, 19, 20, 22, 23	2B1 to 2B8	Data inputs/outputs
24	2DIR	Directional control
25	$\overline{2G}$	Output enable input
36, 35, 33, 32, 30, 29, 27, 26	2A1 to 2A8	Data inputs/outputs
47, 46, 44, 43, 41, 40, 38, 38	1A1 to 1A8	Data inputs/outputs
48	$\overline{1G}$	Output enable input
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0 V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

2.3 Truth table

Table 2. Truth table

Inputs		Function		Output
\overline{G}	DIR	A bus	B bus	Yn
L	L	OUTPUT	INPUT	A = B
L	H	INPUT	OUTPUT	B = A
H	X	Z	Z	Z

Note: X = do not care; Z = high impedance

3 Maximum ratings

Stressing the device above the rating listed in the “absolute maximum ratings” table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	-0.5 to +4.6	V
V_I	DC input voltage	-0.5 to +4.6	V
V_O	DC output voltage (OFF-state)	-0.5 to +4.6	V
V_O	DC output voltage (high or low-state) ⁽¹⁾	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC input diode current	- 50	mA
I_{OK}	DC output diode current ⁽²⁾	- 50	mA
I_O	DC output current	± 50	mA
I_{CC} or I_{GND}	DC V_{CC} or ground current per supply pin	± 100	mA
P_D	Power dissipation	400	mW
T_{stg}	Storage temperature	-65 to +150	°C
T_L	Lead temperature (10 s)	260	°C
R_{thjc}	Thermal resistance junction-to-case ⁽³⁾	22	°C/W
ESD	HBM ⁽⁴⁾ as MIL STD 883 method 3015	2	kV

- I_O absolute maximum ratings must be observed
- $V_O < GND$, $V_O > V_{CC}$
- Short-circuits can cause excessive heating and destructive dissipation. Values are typical.
4. Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 k Ω resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.

3.1 Recommended operating conditions

Table 4. Recommended operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	1.8 to 3.6	V
V_I	Input voltage	-0.3 to 3.6	V
V_O	Output voltage (OFF-state)	0 to 3.6	V
V_O	Output voltage (high or low-state)	0 to V_{CC}	V
I_{OH}, I_{OL}	High or low level output current ($V_{CC} = 3.0$ to 3.6 V)	± 12	mA
I_{OH}, I_{OL}	High or low level output current ($V_{CC} = 2.3$ to 2.7 V)	± 8	mA
T_{op}	Operating temperature	-55 to 125	°C
dt/dv	Input rise and fall time ⁽¹⁾	0 to 10	ns/V

1. V_{IN} from 0.8 V to 2 V at $V_{CC} = 3.0$ V

4 Electrical characteristics

Table 5. DC specifications

Symbol	Parameter	Test conditions		Value		Unit
		V _{CC} (V)		-55 to 125 °C		
				Min.	Max.	
V _{IC}	Negative input clamp voltage	1.8 to 3.6	I _{IN} = -1 mA	-0.4	-1.5	V
	Functional tests	3.6	V _{IN} = V _{IH} min or V _{IL} max, verify output V _{OUT}	L	H	
		2.3		L	H	
		1.8		L	H	
V _{IH}	High level input voltage	3.6		2		V
		3		2		
		2.7		2		
		2.3		1.6		
		1.8		1.2		
V _{IL}	Low level input voltage	3.6			0.8	V
		3			0.8	
		2.7			0.8	
		2.3			0.7	
		1.8			0.4	
V _{OH}	High level output voltage	3.6	I _O = -100 μA	3.4		V
		3	I _O = -8 mA	2.4		
			I _O = -12 mA	2.2		
		2.7	I _O = -100 μA	2.5		
			I _O = -6 mA	2.2		
		2.3	I _O = -6 mA	1.8		
			I _O = -8 mA	1.7		
1.8	I _O = -4 mA	1.4				

Table 5. DC specifications

Symbol	Parameter	Test conditions		Value		Unit
		V _{CC} (V)		-55 to 125 °C		
				Min.	Max.	
V _{OL}	Low level output voltage	3.6	I _O = 100 μA		0.2	V
		3	I _O = 8 mA		0.55	
			I _O = 12 mA		0.8	
		2.7	I _O = 100 μA		0.2	
			I _O = 6 mA		0.4	
		2.3	I _O = 6 mA		0.4	
I _O = 8 mA			0.6			
1.8	I _O = 4 mA		0.3			
I _I	Input leakage current	3.6	V _{IN} = 0 V for input under test, V _{IN} = V _{CC} or 0 V for all other input		± 5	μA
I _{CC}	Quiescent supply current, output high or low	3.6	V _{IN} = V _{CC} or 0 V		100	μA
I _{CCZ}	Quiescent supply current, output three-state	3.6	V _{IN} = V _{CC} or 0 V		100	μA
ΔI _{CC}	Quiescent supply current delta, TTL input level	3.6	input under test: V _{IN} = V _{CC} - 0.6 V for all other inputs: V _{IN} = V _{CC} or 0 V		750	μA
I _{I(HOLD)}	Input hold current	3	V _{IN} = V _{IL} = 0.8 V	75		μA
			V _{IN} = V _{IH} = 2.0 V	-75		
I _{OFF}	Power off leakage current	0	V _{IN} or V _O = 0 to 3.6 V		10	μA
I _{OZ}	High impedance output leakage current	3.6	V _{IN} = V _{IH} or V _{IL} V _O = 0 or 3.6 V		± 10	μA

Table 6. Dynamic switching characteristics

Symbol	Parameter	Test condition		Value		Unit
		V _{CC} (V)		T _A = 25 °C		
				Min.	Max.	
V _{OLP}	Low level ground bounce noise ⁽¹⁾	3.3	V _{IL} = 0 V, V _{IH} = V _{CC} C _L = 30 pF, R _L = 500 Ω 25 °C	4	750	mV
V _{OLV}				4	-300	
V _{OHP}	High level ground bounce noise ⁽¹⁾	3.3		4	1200	mV
V _{OHV}				4	-120	

1. Guaranteed by design.



$$C_L = 30 \text{ pF}, R_L = 500 \text{ } \Omega$$

Table 7. AC electrical characteristics

Symbol	Parameter	Test conditions		Value		Unit
		V_{CC} (V)		-55 to 125 °C		
				Min.	Max.	
t_{PLH} t_{PHL}	Propagation delay time	3.6		0.8	4.0	ns
		2.3		1.0	4.9	
		1.8		1.0	8.7	
t_{PZL} t_{PZH}	Output enable time	3.6		0.8	4.8	ns
		2.3		1.0	6.8	
		1.8		1.0	10.5	
t_{PLZ} t_{PHZ}	Output disable time	3.6		0.8	7.0	ns
		2.3		1.0	5.7	
		1.8		1.0	8.0	
t_{OSLH} t_{OSHL}	Output to output skew time ⁽¹⁾ ⁽²⁾	2.3 to 2.7			0.5	ns
		3.0 to 3.6			0.5	

1. Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW ($t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$)
2. Parameter guaranteed by design

Table 8. Capacitive characteristics

Symbol	Parameter	Test conditions		Value			Unit
		V_{CC} (V)		$T_A = 25 \text{ } ^\circ\text{C}$			
				Min.	Typ.	Max.	
C_{IN}	Input capacitance	0		4		10	pF
C_{OUT}	Output capacitance	3.3		4		12	pF
C_{PD}	Power dissipation capacitance ⁽¹⁾	3.3	$f_{IN} = 1 \text{ MHz}$	4		80	pF

1. C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to test circuit). Average operating current can be obtained by the following equation.
 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/16$ (per circuit)

5 Test circuit

Figure 4. Test circuit

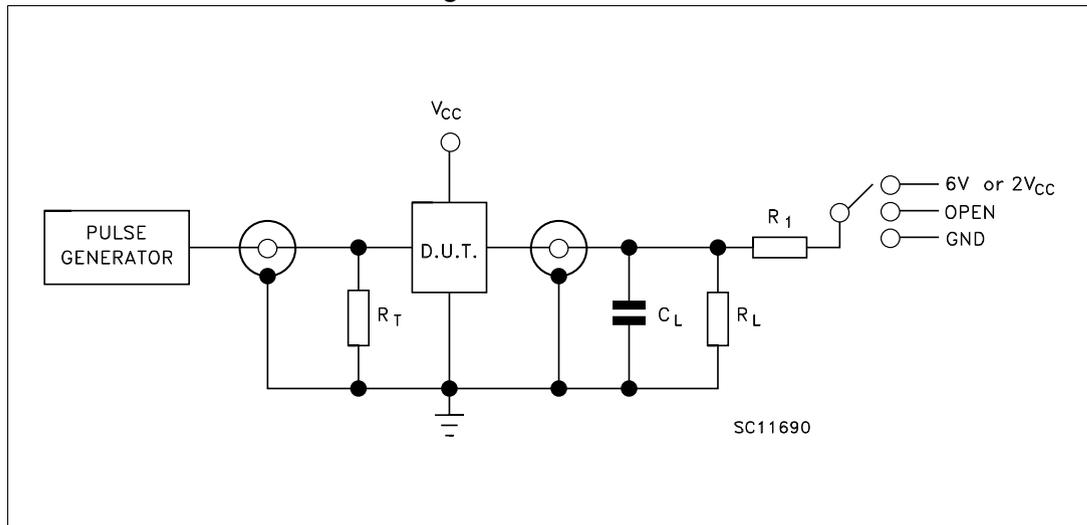


Table 9. Test circuit

Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ} ($V_{CC} = 3.0$ to 3.6 V)	6 V
t_{PZL}, t_{PLZ} ($V_{CC} = 1.8$ to 2.7 V)	$2 V_{CC}$
t_{PZH}, t_{PHZ}	GND

$C_L = 30$ pF or equivalent (includes jig and probe capacitance)

$R_L = R_1 = 500 \Omega$ or equivalent

$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

6 Waveforms

Table 10. Waveform symbol value

Symbol	V _{CC}	
	3.0 to 3.6 V	1.8 V and 2.3 to 2.7 V
V _{IH}	2.7 V	V _{CC}
V _M	1.5 V	V _{CC} /2
V _X	V _{OL} + 0.3 V	V _{OL} + 0.15 V
V _Y	V _{OH} - 0.3 V	V _{OH} - 0.15 V

Figure 5. Waveform - propagation delay (f = 1 MHz; 50% duty cycle)

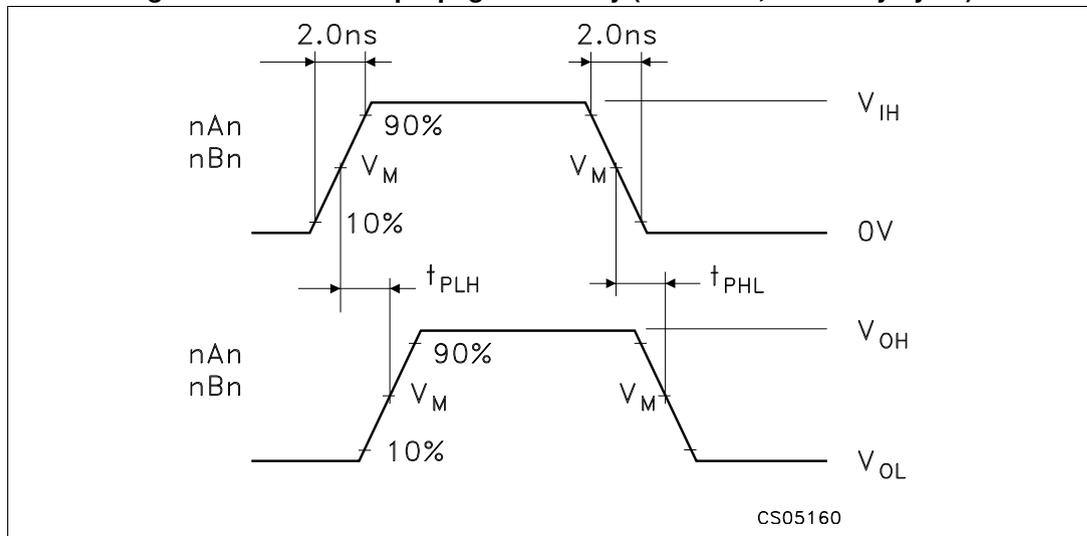
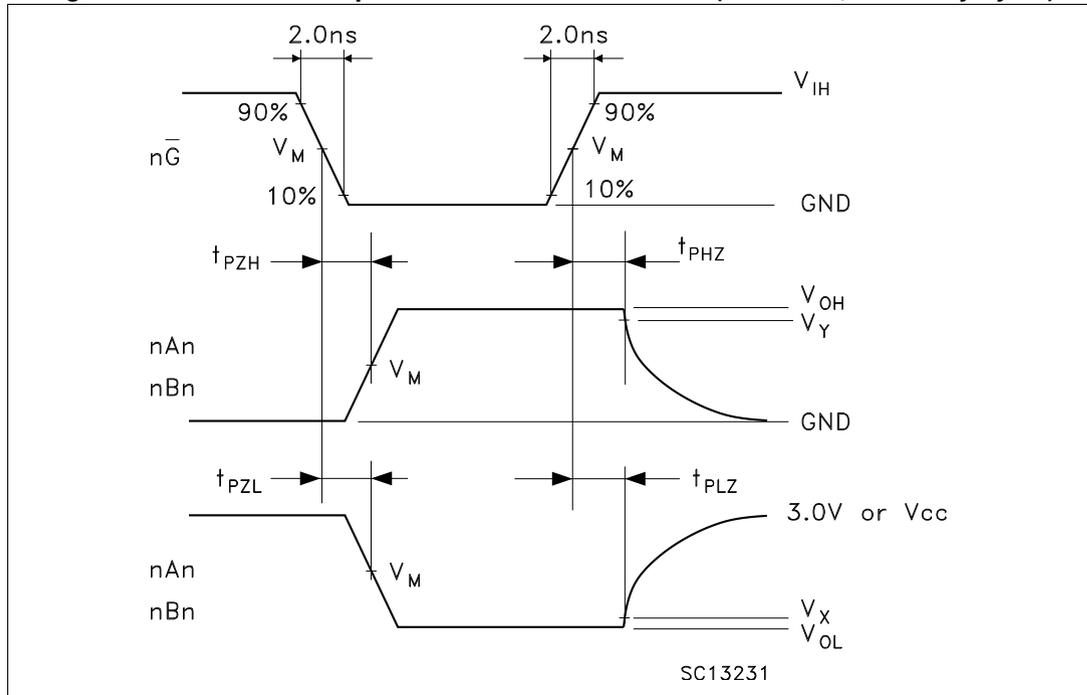


Figure 6. Waveform - output enable and disable time (f = 1 MHz; 50% duty cycle)



7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Figure 7. Flat-48 (MIL-STD-1835) package outline

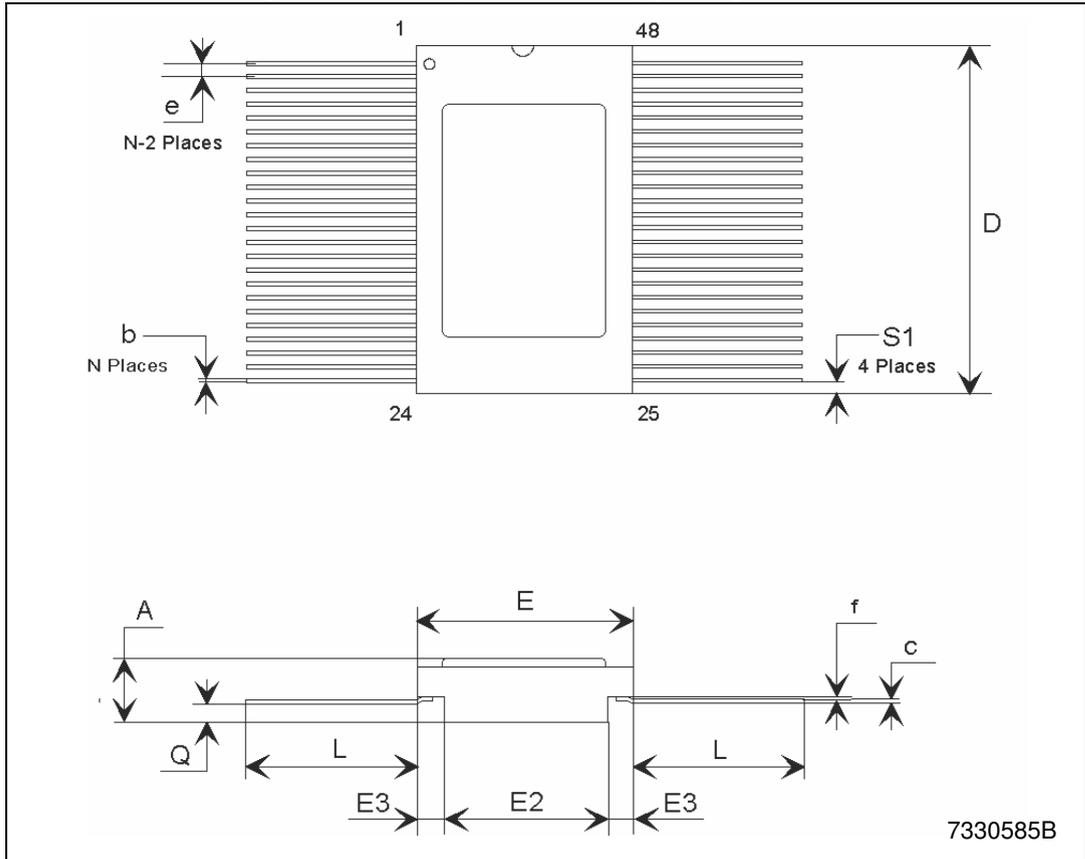


Table 11. Flat-48 (MIL-STD-1835) mechanical data

Dim.	mm			inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.18	2.47	2.72	0.086	0.097	0.107
b	0.20	0.254	0.30	0.008	0.010	0.012
c	0.12	0.15	0.18	0.005	0.006	0.007
D	15.57	15.75	15.92	0.613	0.620	0.627
E	9.52	9.65	9.78	0.375	0.380	0.385
E2	6.22	6.35	6.48	0.245	0.250	0.255
E3	1.52	1.65	1.78	0.060	0.065	0.070
e		0.635			0.025	
f		0.20			0.008	
L	6.85	8.38	9.40	0.270	0.330	0.370
Q	0.66	0.79	0.92	0.026	0.031	0.036
S1	0.25	0.43	0.61	0.010	0.017	0.024

8 Order codes

Table 12. Ordering information

Order code	SMD (1)	Quality level	Package	Marking (2)	Finish.	Pack.
RHRXHR162245K1		Eng. model	Flat-48	RHRXHR162245K1	Gold	Strip pack
RHFXHR162245K03V	5962F05213	QML-V flight		5962F0521302VXC		
RHFXHR162245K05V	5962F05213		Flat-48 with grounded lid	5962F0521302VYC		

- Standard microcircuit drawing
- Specific marking only. Complete marking includes the following:
 - ST logo
 - Date code (date the package was sealed) in YYWWA (year, week, and lot index of week)
 - Country of origin (FR=France)

Other information

Date code:

The date code is structured as engineering model: EM xyywwz

where:

x = 3 (EM only), assembly location Rennes (France)

yy = last two digits of the year

ww = week digits

z = lot index of the week

Product documentation

Each product shipment includes a set of associated documentation within the shipment box. This documentation depends on the quality level of the products, as detailed in the table below.

The certificate of conformance is provided on paper whatever the quality level. For QML parts, complete documentation, including the certificate of conformance, is provided on a CDROM.

Table 13. Product documentation

Quality level	Item
Engineering model	Certificate of conformance including: Customer name Customer purchase order number ST sales order number and item ST part number Quantity delivered Date code Reference to ST datasheet Reference to TN1181 on engineering models ST Rennes assembly lot ID
QML-V flight	Certificate of Conformance including: Customer name Customer purchase order number ST sales order number and item ST part number Quantity delivered Date code Serial numbers Group C reference Group D reference Reference to the applicable SMD ST Rennes assembly lot ID
	Quality control inspection (groups A, B, C, D, E)
	Screening electrical data in/out summary
	Precap report
	PIND (particle impact noise detection) test
	SEM (scanning electronic microscope) inspection report
	X-ray plates

9 Revision history

Table 14. Document revision history

Date	Revision	Changes
09-Jul-2004	1	First release
17-May-2005	2	SMD qualified
19-Jun-2006	3	300 Krad bullet updated, new template, mechanical data updated
11-Apr-2007	4	Updated cover page features
30-Jul-2007	5	Typo in <i>Table 12 on page 16</i>
17-Sep-2008	6	Updated cover page
08-Sep-2009	7	Updated <i>Table 13 on page 17</i>
02-Aug-2011	8	Added <i>Note: on page 16</i> and in the "Pin connections" diagram on the cover page
18-Nov-2019	9	Updated cover page and <i>Table 13: Ordering information</i> . Added <i>Table 14</i>
02-Apr-2024	10	Updated features and description on the cover page, Table 3 , Table 5 , Table 6 , Table 7 , Table 8 and Table 12

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